



CEU1188SA

800V ▲ 0.62Ω ▲ 6.8A ▲ Si MOSFET

SILICON Si MOSFET ▲ SMD type

N-channel enhancement mode

UL94V-0 rated flame retardant epoxy

TO252 (DPAK) package ▲ MSL 3

Super high dense cell density for extremely low $R_{DS(ON)}$

High power and current handling capability

MAXIMUM RATINGS

Parameter ($T_C = 25^\circ\text{C}$, unless otherwise noted)		Characteristics
Drain-Source Voltage	V_{DS}	800V
Gate-Source Voltage	V_{GS}	$\pm 30\text{V}$
Continuous Drain Current at $T_C = 25^\circ\text{C}$	I_D	6.8A
Pulsed Drain Current ^{Note 1}	I_{DM}	27.2A
Maximum Power Dissipation at $T_C = 25^\circ\text{C}$	P_D	89W
Power Dissipation Derating above 25°C	ΔP_D	$0.71\text{W}/^\circ\text{C}$
Single Pulsed Avalanche Energy ^{Note 4}	E_{AS}	172.8mJ
Single Pulsed Avalanche Current ^{Note 4}	I_{AS}	2.4A
Operating and Storage Temperature Range	T_J, T_{STG}	-55°C to $+150^\circ\text{C}$

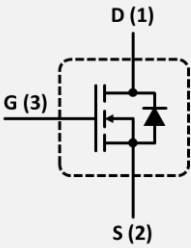
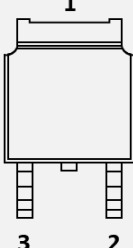
THERMAL CHARACTERISTICS

Parameter	Symbol	Limit
Thermal Resistance, Junction-to-Case	R_{TH_JC}	$1.4^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Ambient	R_{TH_JA}	$50^\circ\text{C}/\text{W}$

APPLICATIONS

Base Station Power	Battery Chargers	LED Lighting	Power Adapters	SMPS
				

PIN DESCRIPTION

Circuit Diagram	Outline - Bottom View	Pin No.	Description
		1 2 3	Drain Source Gate

ELECTRICAL CHARACTERISTICS ▲ $T_C = 25^\circ\text{C}$, unless otherwise noted

Item	Condition	Symbol	Min.	Typ.	Max.	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV_{DSS}	800			V
Zero Gate Voltage Drain Current	$V_{DS} = 800V, V_{GS} = 0V$	I_{DSS}			1	μA
Gate Body Leakage Current, Forward	$V_{GS} = 30V, V_{DS} = 0V$	I_{GSSF}			100	nA
Gate Body Leakage Current, Reverse	$V_{GS} = -30V, V_{DS} = 0V$	I_{GSSR}			-100	nA
On Characteristics ^{Note 2}						
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu A$	$V_{GS(th)}$	2		4	V
Static Drain-Source On-Resistance	$V_{GS} = 10V, I_D = 4A$	$R_{DS(ON)}$		0.62	0.72	Ω
Gate Input Resistance	$f = 1\text{MHz}$, Open Drain	R_G		6.4		Ω
Dynamic Characteristics ^{Note 3}						
Input Capacitance	$V_{DS} = 100V, V_{GS} = 0V, f = 1\text{MHz}$	C_{ISS}		685		pF
Output Capacitance	$V_{DS} = 100V, V_{GS} = 0V, f = 1\text{MHz}$	C_{OSS}		55		pF
Reverse Transfer Capacitance	$V_{DS} = 100V, V_{GS} = 0V, f = 1\text{MHz}$	C_{RSS}		15		pF
Switching Characteristics ^{Note 3}						
Turn-On Delay Time	$V_{DD} = 400V, V_{GS} = 10V, I_D = 4A, R_{G(ext)} = 10\Omega$	$t_{D(ON)}$		25		ns
Turn-On Rise Time	$V_{DD} = 400V, V_{GS} = 10V, I_D = 4A, R_{G(ext)} = 10\Omega$	t_R		9		ns
Turn-Off Delay Time	$V_{DD} = 400V, V_{GS} = 10V, I_D = 4A, R_{G(ext)} = 10\Omega$	$t_{D(OFF)}$		45		ns
Turn-Off Fall Time	$V_{DD} = 400V, V_{GS} = 10V, I_D = 4A, R_{G(ext)} = 10\Omega$	t_F		10		ns
Total Gate Charge	$V_{DD} = 640V, V_{GS} = 10V, I_D = 4A$	Q_G		17		nC
Gate Source Charge	$V_{DD} = 640V, V_{GS} = 10V, I_D = 4A$	Q_{GS}		3		nC
Gate Drain Charge	$V_{DD} = 640V, V_{GS} = 10V, I_D = 4A$	Q_{GD}		6		nC
Drain-Source Diode Characteristics and Maximum Ratings						
Drain-Source Diode Forward Current		I_S			6.8	A
Drain-Source Diode Forward Voltage ^{Note 2}	$V_{GS} = 0V, I_S = 4A$	V_{SD}			1.5	V
Reverse Recovery Time	$I_F = 4A, di/dt = 100A/\mu s$	t_{RR}		341.4		ns
Reverse Recovery Charge	$I_F = 4A, di/dt = 100A/\mu s$	Q_{RR}		1.89		μC
Peak Reverse Recovery Current	$I_F = 4A, di/dt = 100A/\mu s$	I_{RR}		10.67		A

Notes

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2: Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
- 3: Guaranteed by design, not subject to production testing.
- 4: $L = 60\text{mH}$, $I_{AS} = 2.4A$, $V_{DD} = 50V$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$

REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE

Fig. 1 • Output Characteristics

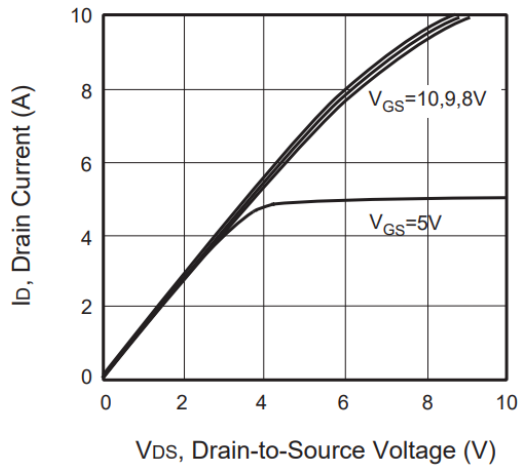


Fig. 2 • Transfer Characteristics

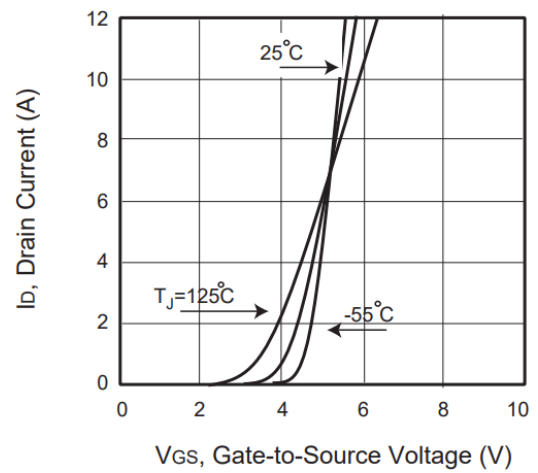


Fig. 3 • Capacitance

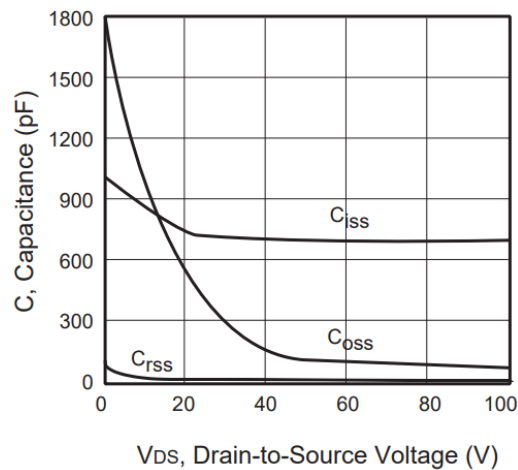


Fig. 4 • On-Resistance Variation with Temperature

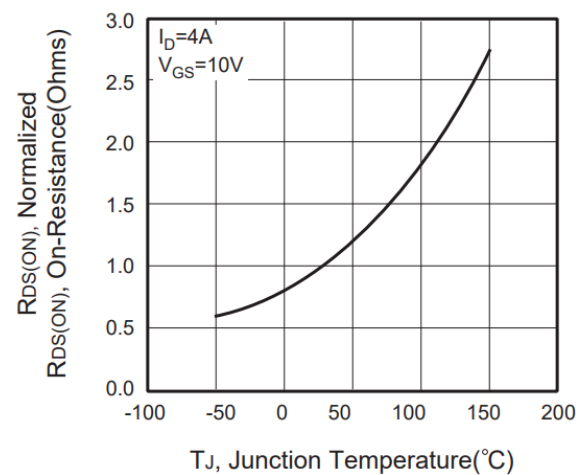


Fig. 5 • Gate Threshold Variation with Temperature

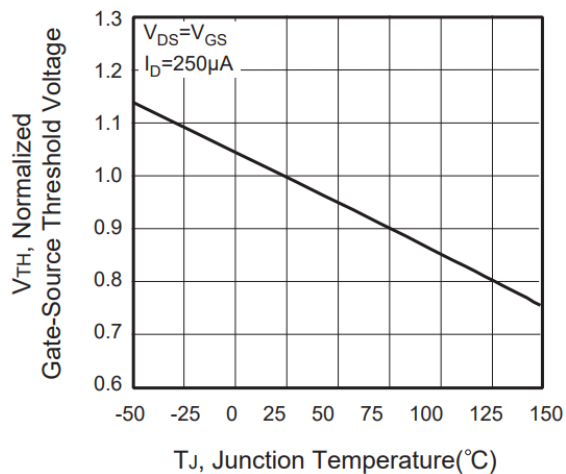
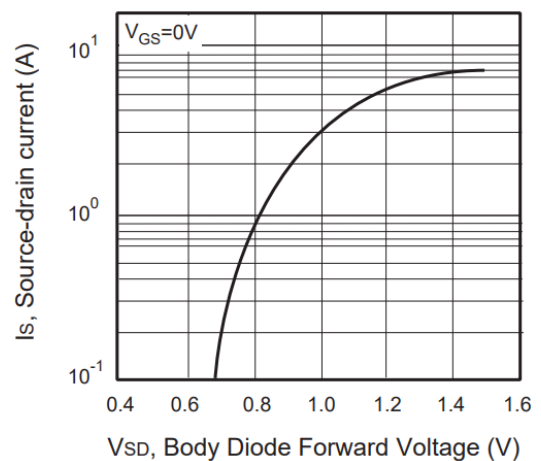


Fig. 6 • Body Diode Forward Voltage Variation with Source Current



REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE

Fig. 7 • Gate Charge

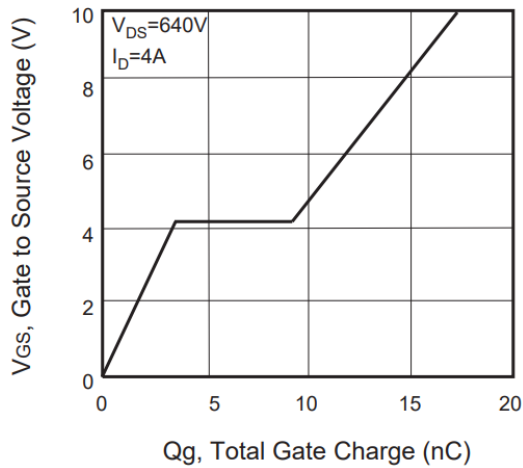


Fig. 8 • Maximum Safe Operating Area

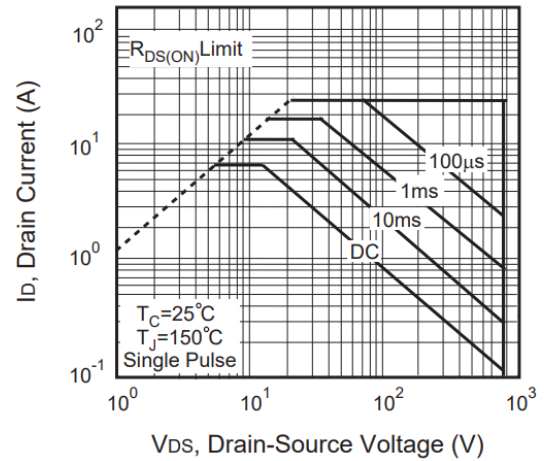


Fig. 9 • Breakdown Voltage Variation vs. Temperature

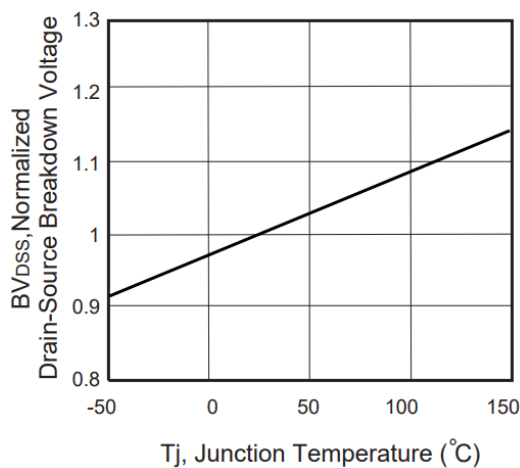


Fig. 10 • Switching Test Circuit

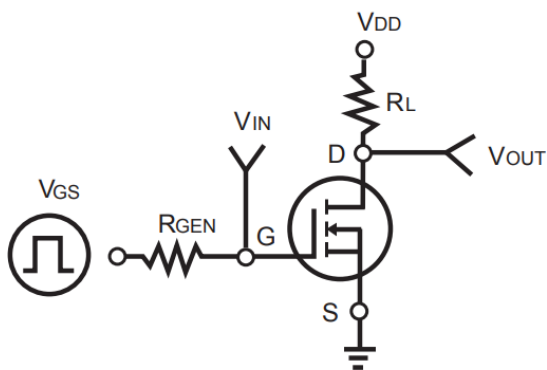
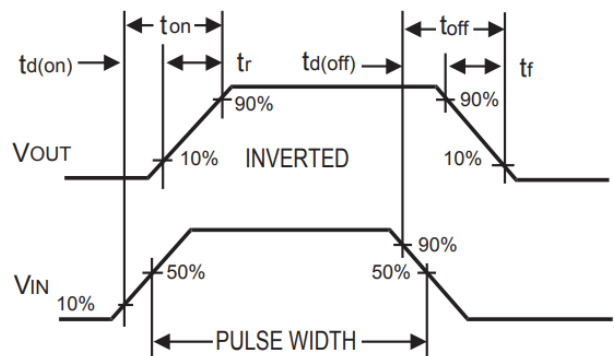
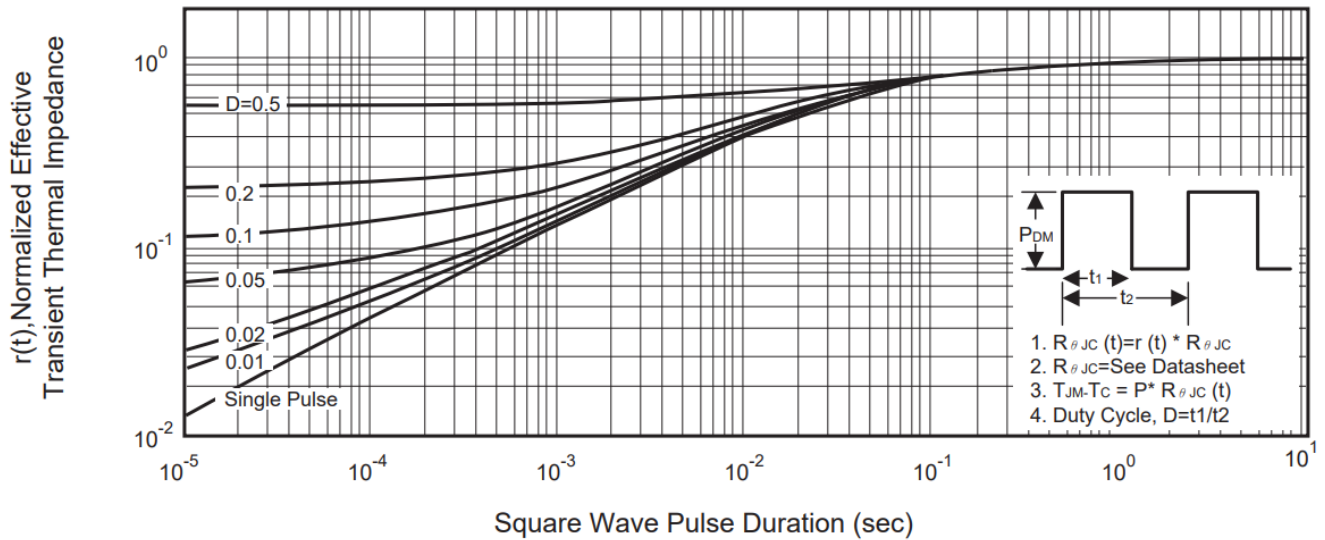


Fig. 11 • Switching Waveforms

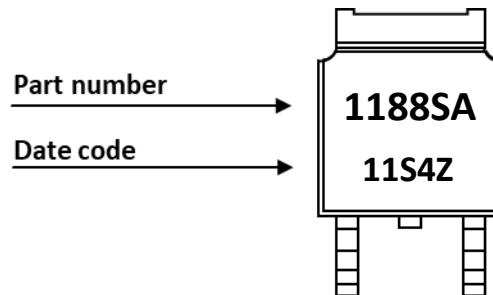


REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE

Fig. 12 ▪ Normalized Thermal Transient Impedance Curve

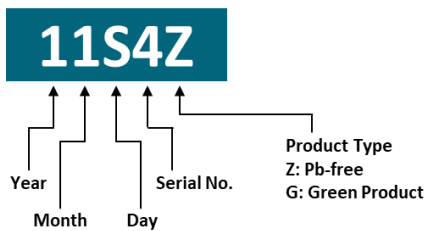


PART MARKING



DATE CODE

Example: 11S4Z



Coding list for „Day“

1	2	3	4	5	6	7	8	9	A
01	02	03	04	05	06	07	08	09	10
B	C	D	E	F	G	H	I	J	K
11	12	13	14	15	16	17	18	19	20
L	M	N	O	P	Q	R	S	T	U
21	22	23	24	25	26	27	28	29	30
V									
31									

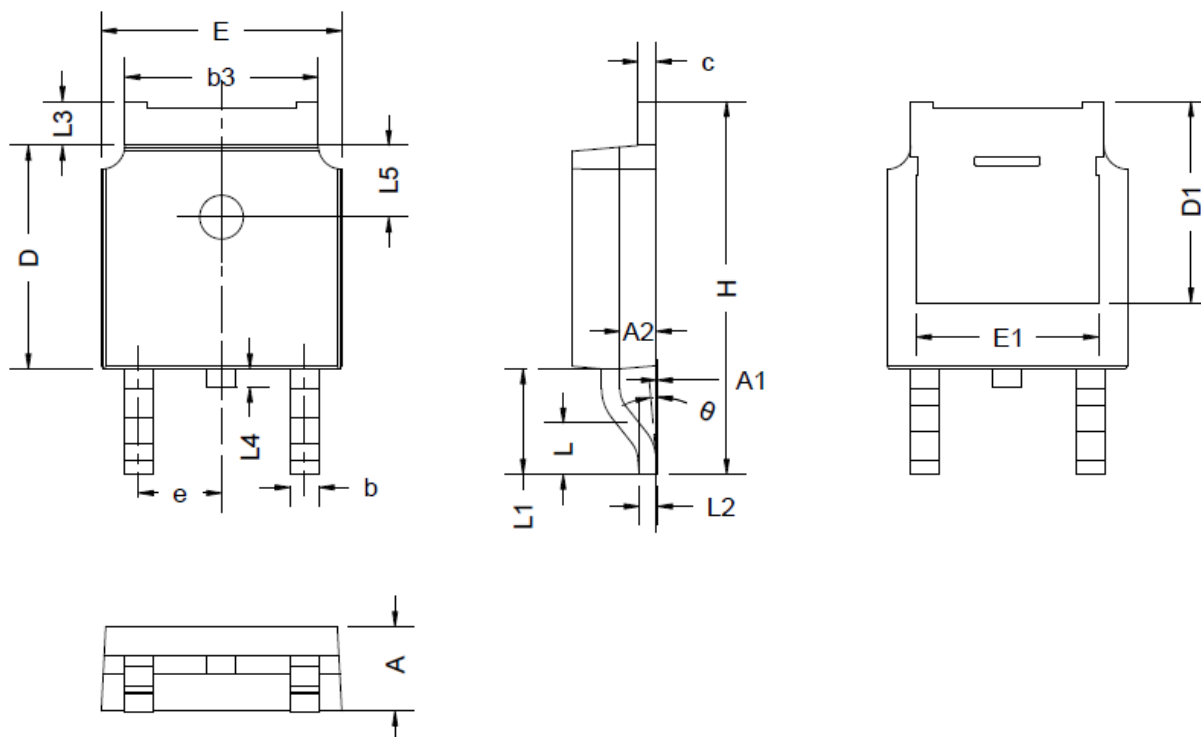
Coding list for „Month“

1	2	3	4	5	6
Jan	Feb	Mar	Apr	May	Jun
7	8	9	A	B	C
Jul	Aug	Sep	Oct	Nov	Dec

Coding list for „Year“

0	1	2	3	4
2020	2021	2022	2023	2024
5	6	7	8	9
2025	2026	2027	2028	2029

PACKAGE OUTLINE



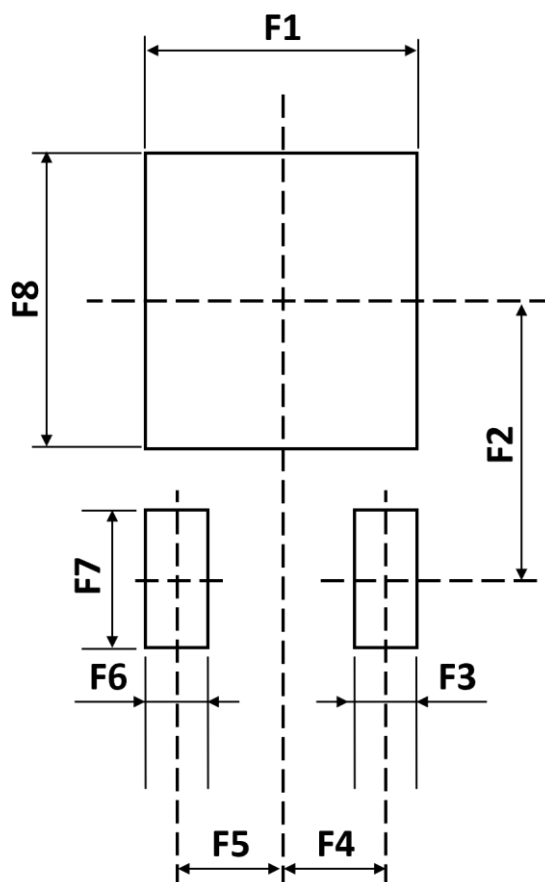
Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
A	2.20	2.30	2.38
A1	0.00	-	0.20
A2	0.90	1.07	1.17
b	0.68	0.78	0.90
b3	5.23	5.33	5.46
c	0.43	0.53	0.61
D	5.98	6.10	6.22
D1	5.30 REF		
E	6.40	6.60	6.73
E1	4.63	-	-

Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
e		2.286 BSC	
H	9.40	10.10	10.50
L	1.38	1.50	1.75
L1	2.90 REF		
L2	0.51 BSC		
L3	0.88	-	1.28
L4	0.50	.	1.00
L5	1.65	1.80	1.95
theta	0°	-	8°

ORDERING INFORMATION

Part Number	Package	Packing	Reel Qty.	Inner Box Qty.	Outer Box Qty.
CEU1188SA	TO252 (DPAK)	Reel	2,500pcs	5,000pcs	40,000pcs

RECOMMENDED PAD LAYOUT



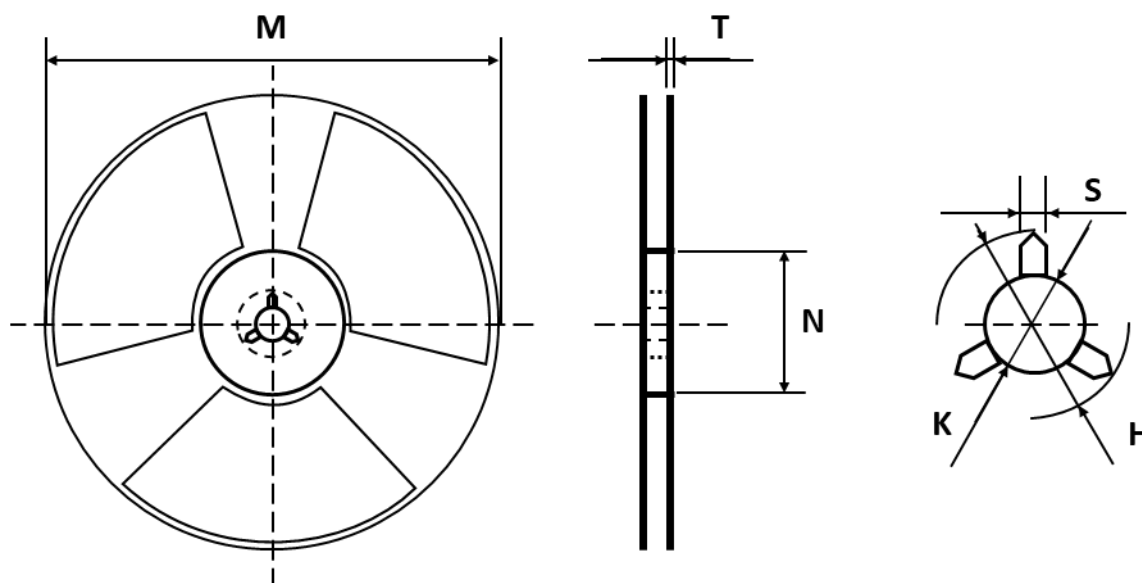
Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
F1	-	6.00	-
F2	-	6.25	-
F3	-	1.40	-
F4	-	2.29	-

Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
F5	-	2.29	-
F6	-	1.40	-
F7	-	3.00	-
F8	-	6.50	-

Notes:

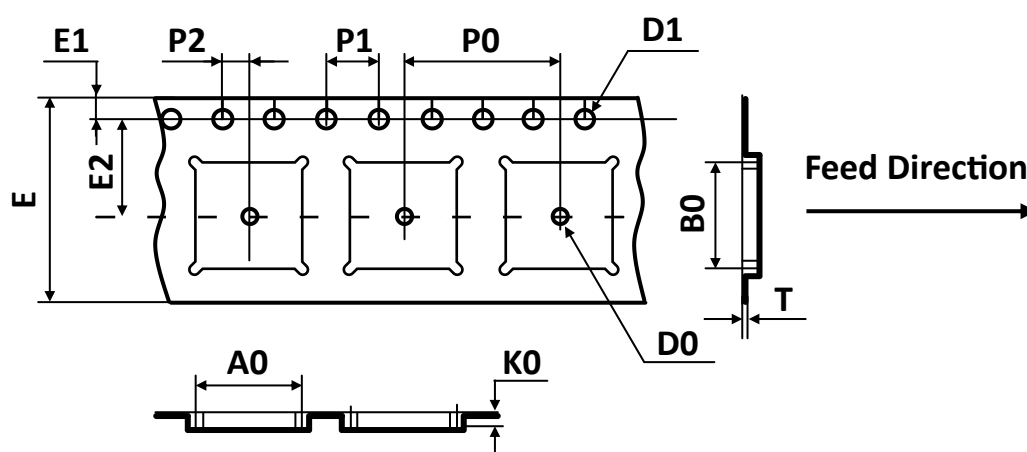
1. The suggested land pattern dimensions have been provided for reference only.
2. For further information, please reference document IPC-7351A.

REEL DIMENSIONS ▲ All dimensions in mm



Tape Size	Reel Size	M	N	T	H	K	S
16mm	Ø330	Ø330.00	Ø100.00	2.10	22.00	13.00	2.00
		±2.00	±0.50	±0.20	±0.50	+0.50 -0.20	+0.50 -0.20

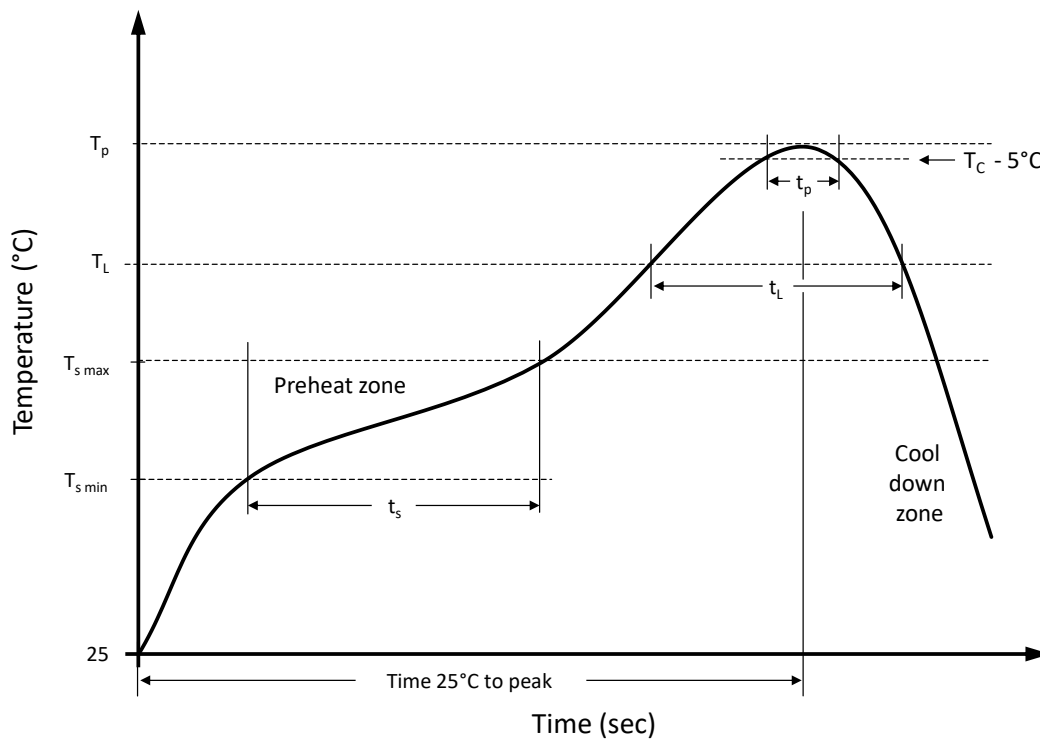
TAPE DIMENSIONS ▲ All dimensions in mm



Package	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
TO252 (DPAK)	6.90	10.50	2.70	1.50	1.50	16.00	1.75	7.50	8.00	4.00	2.00	0.30
	±0.10	±0.10	±0.10	MIN	±0.10	+0.30 -0.20	±0.10	±0.10	±0.10	±0.10	±0.10	±0.05

Note: All dimensions meet EIA-481-D requirements.

RECOMMENDED REFLOW SOLDERING PROFILE



Recommended reflow soldering conditions ▲ Refer to JEDEC J-STD-020E

Profile Features		Sn-Pb Eutetic Assembly	Pb-Free Assembly
Preheat temperature min.	T _{s min}	100 °C	150 °C
Preheat temperature max.	T _{s max}	150 °C	200 °C
Preheat time t _s from T _{s min} to T _{s max}	t _s	120 seconds	120 seconds
Ramp-up rate (T _L to T _p)		max. 3 °C/second	max. 3 °C/second
Liquidous temperature	T _L	183 °C	217 °C
Time t _L maintained above T _L	t _L	150 seconds max.	150 seconds max.
Peak package body temperature	T _p	235°C	260°C
Timeframe of within 5°C below and up to max actual peak body temperature	t _p	20 seconds max.	30 seconds max.
Ramp-down rate (T _L to T _p)		max. 6 °C/second	max. 6 °C/second
Time 25°C to peak temperature		max. 6 minutes	max. 8 minutes

REVISION TABLE

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

DISCLAIMER

Except for the written expressed warranties, MGT does not implicitly, by assumption or whatever else, warrant, under-take, promise any other warranty or guaranty for any MGT product.

All information and technical specifications made available by MGT are for guidance only and we reserve the right to change or modify them without prior notice. Unless expressly stated in writing by MGT, we reject any guarantees, obligations, or warranties.

All MGT products with the technical specifications described are suitable for use in certain applications. Operating, production, storage and environmental conditions can have a massive influence on the parameters mentioned in the data sheets, which cause the performance to vary over time.

It is subject to the user's duty of care to design and validate his products in such a way that appropriate measures are taken, such as protective circuits or redundant systems to ensure the safety standards required in the application.

MGT components are not designed or rated for use in life support, rescue, safety critical, military, or aerospace applications where failure or malfunction could result in property or environmental damage, serious injury or death. In the aforementioned cases, please contact us before using MGT products.

In principle, we reserve all rights and MGT's general terms and conditions apply. You can find them on our website www.mgt.co.com.